

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
60V	23m Ω @10V	5.5A
	30m Ω @4.5V	



合肥矽普半导体

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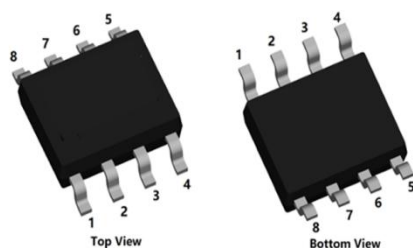
Feature

- Fast Switching
- Low Gate Charge and Rdson
- 100% Single Pulse avalanche energy Test

Applications

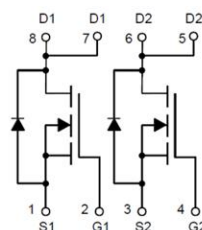
- Power Switching Application
- Hard switched and high frequency circuits
- Uninterruptible Power Supply

Package

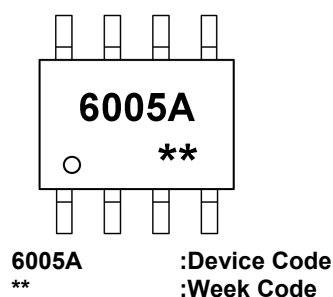


SOP-8L

Circuit Diagram



Marking



Order Information

Device	Package	Unit/Tape
SP6005ADP8	SOP-8L	4000

Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	5.5	A
Pulsed Drain Current	I_{DM}	22	A
Single Pulse Avalanche Energy ¹	E_{AS}	20	mJ
Power Dissipation	P_D	2.5	W
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	50	°C/W
Storage Temperature Range	T_{STG}	-55 to 150	°C
Operating Junction Temperature Range	T_J	-55 to 150	°C

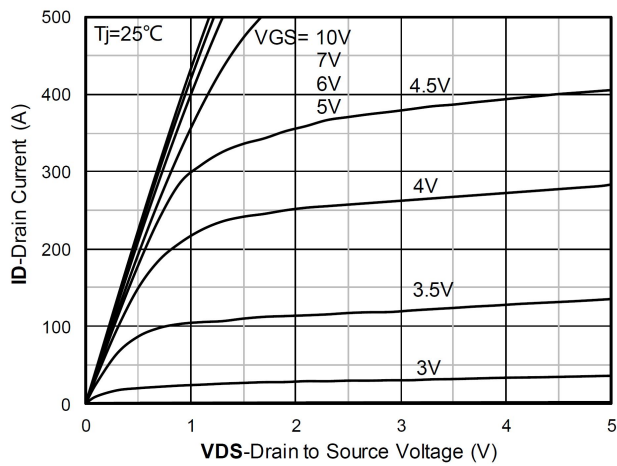
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V , ID=250uA	60	-	-	V
Drain-Source Leakage Current	IDSS	VDS=48V , VGS=0V	-	-	1	uA
Gate-Source Leakage Current	IGSS	VGS=±20V , VDS=0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	VGS=VDS , ID =250uA	1.0	1.5	2.5	V
Static Drain-Source On-Resistance	RDS(ON)	VGS=10V , ID=5A	-	23	35	mΩ
		VGS=4.5V , ID=3A	-	30	45	
Dynamic characteristics						
Input Capacitance	Ciss	VDS=15V , VGS=0V , f=1MHz	-	1304	-	pF
Output Capacitance	Coss		-	123	-	
Reverse Transfer Capacitance	Crss		-	97	-	
Total Gate Charge	Qg	VDS=30V , VGS=10V , ID=10A	-	25.3	-	nC
Gate-Source Charge	Qgs		-	4.7	-	
Gate-Drain Charge	Qgd		-	6.1	-	
Switching Characteristics						
Turn-On Delay Time	Td(on)	VDD=30V, VGS=10V , RG=3Ω, ID=2A	-	6	-	nS
Rise Time	Tr		-	6.1	-	
Turn-Off Delay Time	Td(off)		-	17	-	
Fall Time	Tf		-	3	-	
Diode Characteristics						
Diode Forward Voltage	VSD	VGS=0V , IS=1A	-	-	1.2	V
Maximum Body-Diode Continuous Current	IS		-	-	5.5	A
Reverse Recovery Time	Trr	Is=5A, di/dt=100A/us, Tj=25°C	-	24	-	nS
Reverse Recovery Charge	Qrr		-	21	-	nC

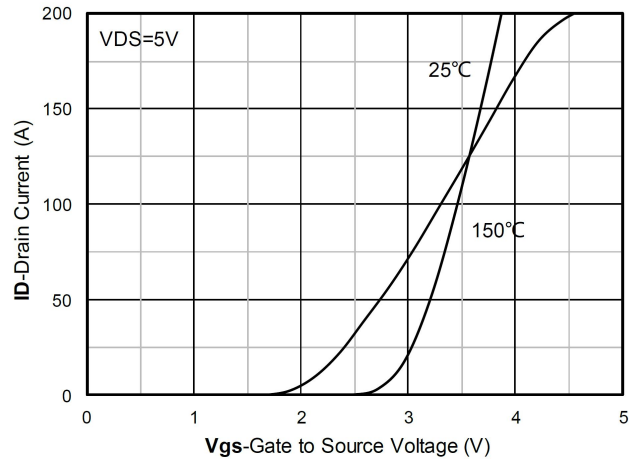
Note :

1. The test condition is $V_{DD}=30V$, $V_{GS}=10V$, $L=0.5mH$, $R_G=25\Omega$

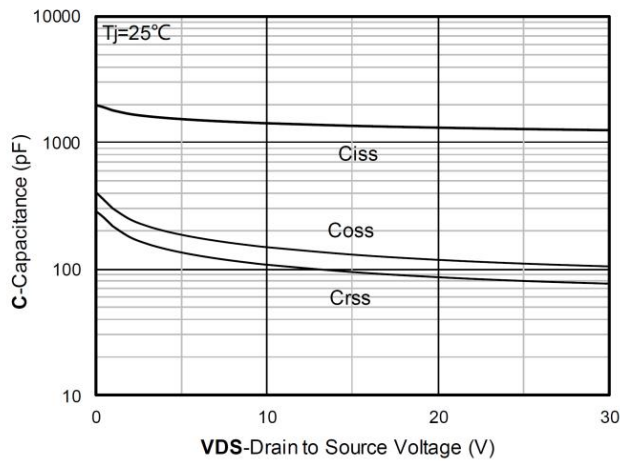
Typical Characteristics



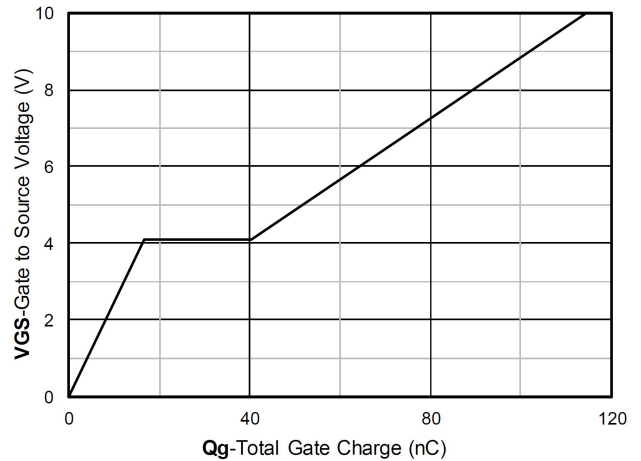
Output Characteristics



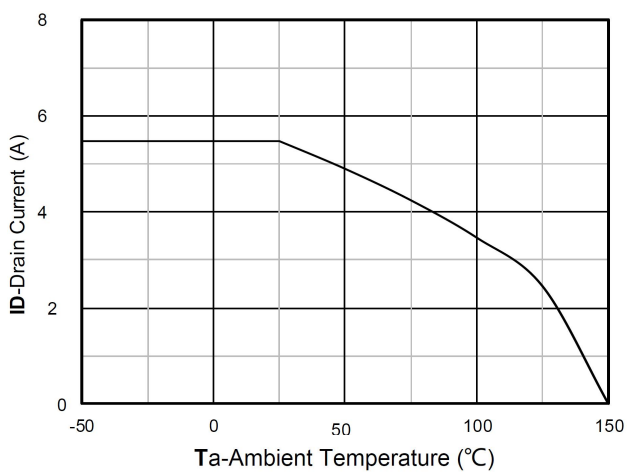
Transfer Characteristics



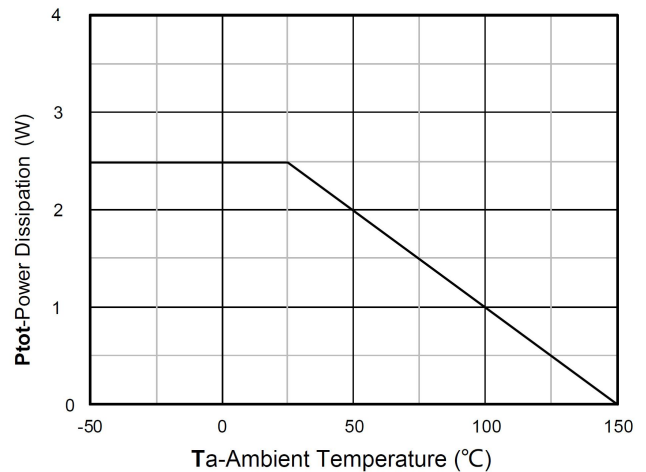
Capacitance Characteristics



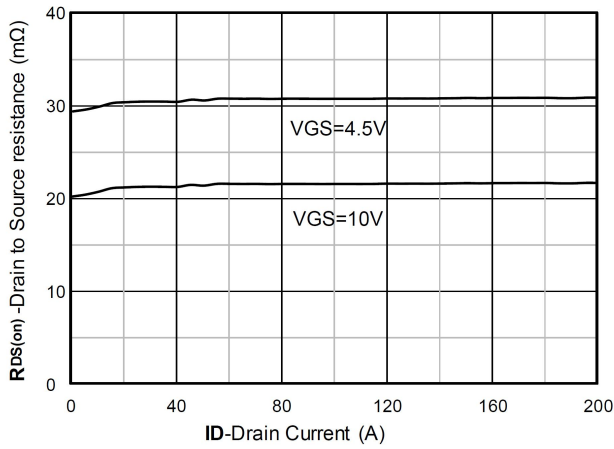
Gate Charge



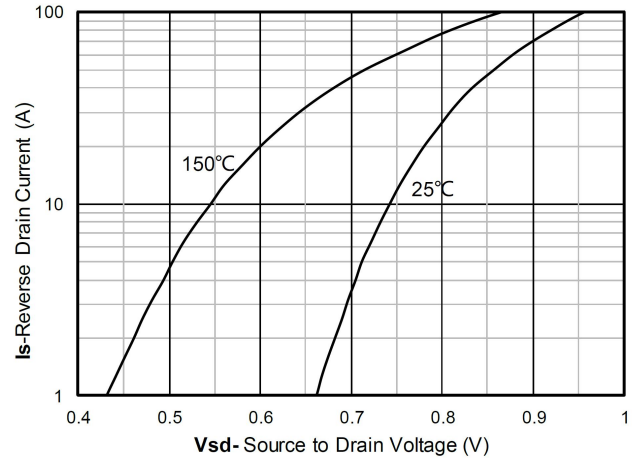
Current dissipation



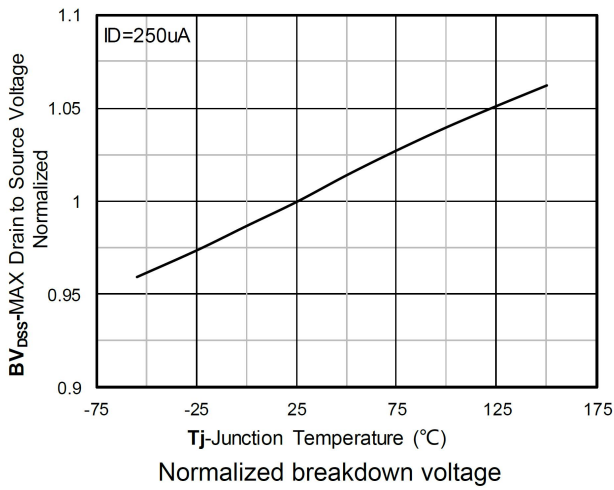
Power dissipation



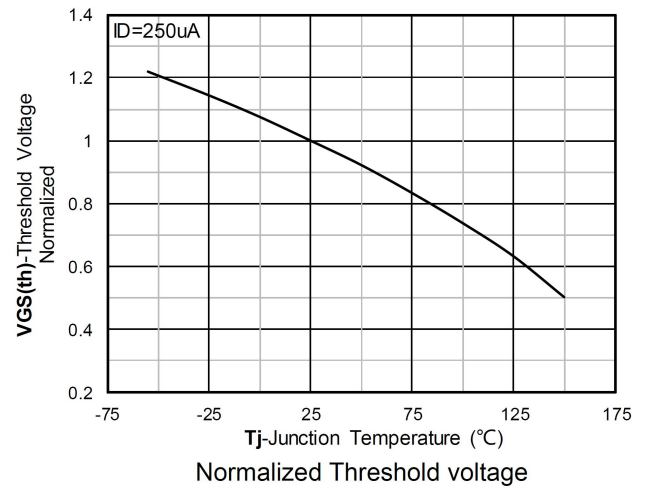
$R_{DS(on)}$ VS Drain Current



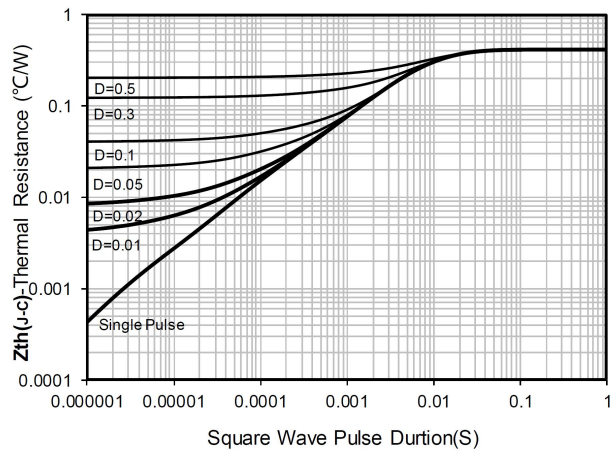
Forward characteristics of reverse diode



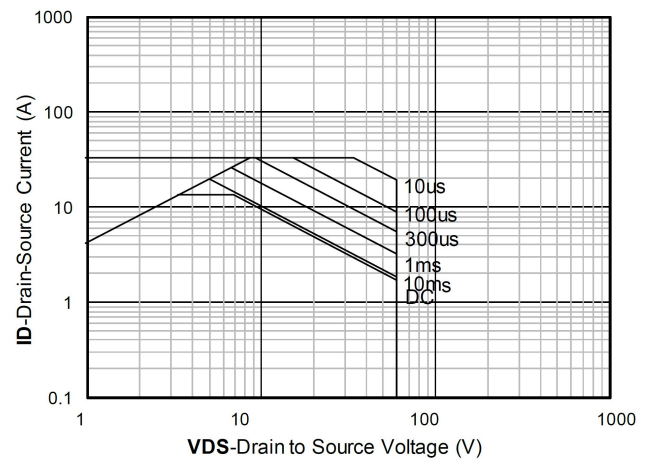
Normalized breakdown voltage



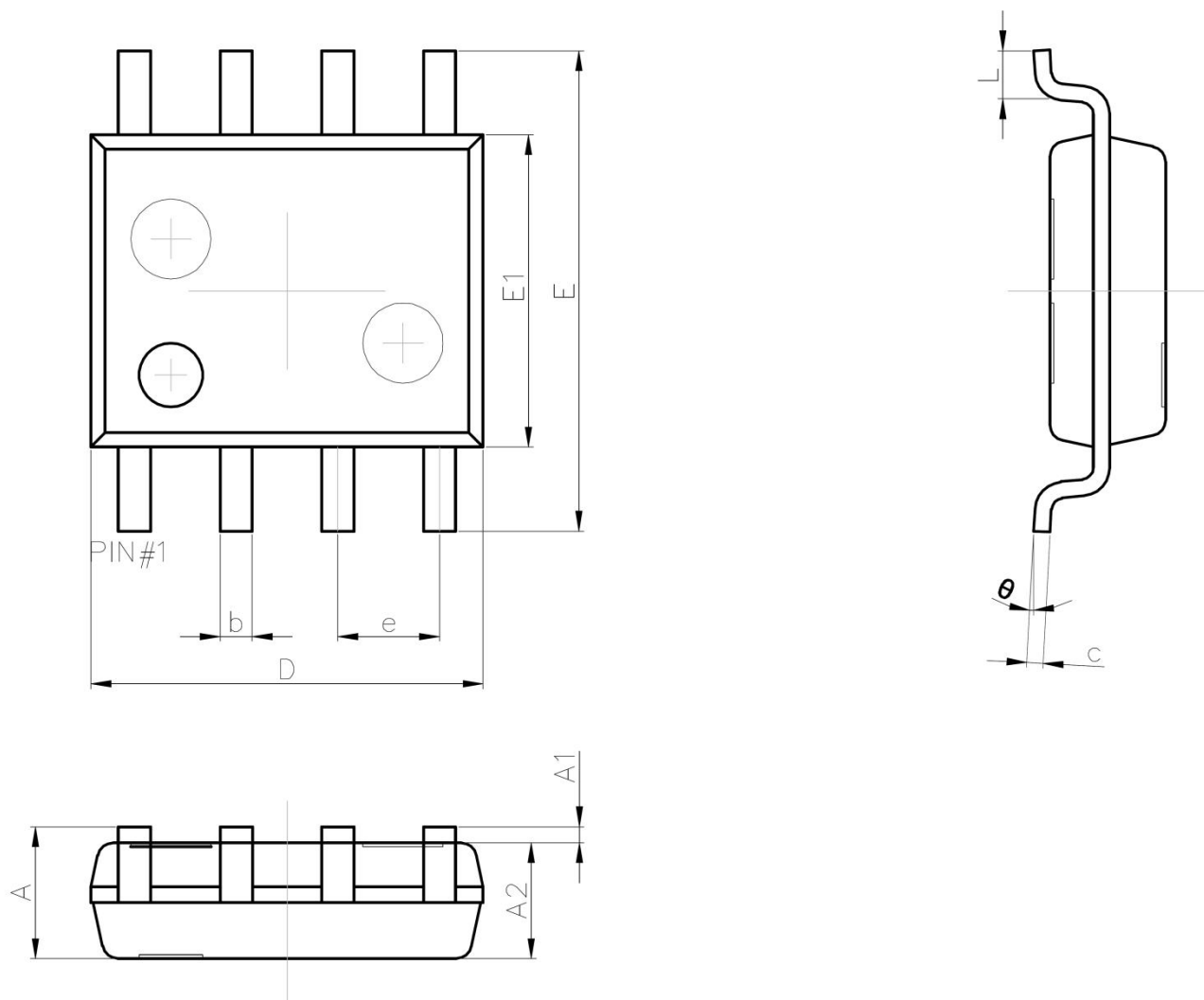
Normalized Threshold voltage



Maximum Transient Thermal Impedance



Safe Operation Area

SOP-8L Package Information


Symbol	Dimensions In Millimeters	
	Min.	Max.
A	1.35	1.75
A1	0.10	0.25
A2	1.35	1.55
b	0.33	0.51
c	0.17	0.25
D	4.80	5.00
e	1.27 REF.	
E	5.80	6.20
E1	3.80	4.00
L	0.40	1.27
θ	0°	8°

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